

#### **Product Features**

InGaP HBT Gain Block

- DC 6000 MHz
- +6.5 dBm P1dB at 900 MHz
- +19 dBm OIP3 at 900 MHz
- 11 dB Gain at 900 MHz
- Single Voltage Supply
- Green SOT-363 SMT Pkg.
- Internally matched to 50  $\Omega$

### **Applications**

- Mobile Infrastructure
- CATV / DBS
- W-LAN / ISM
- RFID
- Defense / Homeland Security
- Fixed Wireless

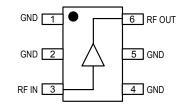
#### **Product Description**

The AG201-63 is a general-purpose buffer amplifier that offers high dynamic range in a low-cost surface-mount package. At 900 MHz, the AG201-63 typically provides 11 dB gain, +19 dBm OIP3, and +6.5 dBm P1dB. The device combines dependable performance with consistent quality to maintain MTTF values exceeding 100 years at mounting temperatures of +85° C and is housed in a lead-free/green/RoHS-compliant SOT-363 industry standard SMT package.

The AG201-63 consists of Darlington pair amplifiers using the high reliability InGaP/GaAs HBT technology process technology and only requires DC-blocking capacitors, a bias resistor, and an inductive RF choke for operation.

The broadband MMIC amplifier can be directly applied to various current and next generation wireless technologies such as GPRS, GSM, CDMA, and W-CDMA. In addition, the AG201-63 will work for other various applications within the DC to 6 GHz frequency range such as CATV and fixed wireless.

#### **Functional Diagram**



Function	Pin No.
Input	3
Output/Bias	6
Ground	1, 2, 4, 5

# Specifications (1)

Parameter	Units	Min	Тур	Max
Operational Bandwidth	MHz	DC		6000
Test Frequency	MHz		900	
Gain	dB		11.3	
Input Return Loss	dB		25	
Output Return Loss	dB		16	
Output IP3 (2)	dBm		+19.1	
Output IP2	dBm		+27	
Output P1dB	dBm		+6.5	
Noise Figure	dB		4.4	
Test Frequency	MHz		1900	_
Gain	dB	10	11	12
Output IP3 (2)	dBm		+18.5	
Output P1dB	dBm		+5.8	
Device Voltage	V		4.0	
Device Current	mA		20	

- 1. Test conditions:  $T = 25^{\circ}$  C, Supply Voltage = +5 V,  $R_{bias} = 49.9 \Omega$ , 50  $\Omega$  System.
- 2.3 3OIP measured with two tones at an output power of -10 dBm/tone separated by 10 MHz. The suppression on the largest IM3 product is used to calculate the 3OIP using a 2:1 rule.

# Typical Performance (1)

Parameter	Units	Typical						
Frequency	MHz	500	900	1900	2140			
S21	dB	11.4	11.3	11	10.9			
S11	dB	-30	-25	-20	-15			
S22	dB	-16	-16	-16	-16			
Output P1dB	dBm	+6.5	+6.5	+5.8	+5.1			
Output IP3	dBm	+19.5	+19.1	+18.5	+18.2			
Noise Figure	dB	4.3	4.4	4.6	4.6			

### **Absolute Maximum Rating**

Parameter	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-55 to +125 °C
DC Voltage	+4.5 V
RF Input Power (continuous)	+10 dBm
Junction Temperature	+250 °C

Operation of this device above any of these parameters may cause permanent damage.

### **Ordering Information**

Part No.	Description
AG201-63*	InGaP HBT Gain Block (lead-tin SOT-363 Pkg)
AG201-63G	InGaP HBT Gain Block (lead-free/green/RoHS-compliant SOT-363 Pkg)
AG201-63PCB	700 – 2400 MHz Fully Assembled Eval. Board

\* This package is being phased out in favor of the green package type which is backwards compatible for existing designs. Refer to Product Change Notification WJPCN06MAY05TC1 on the WJ website.

Specifications and information are subject to change without notice

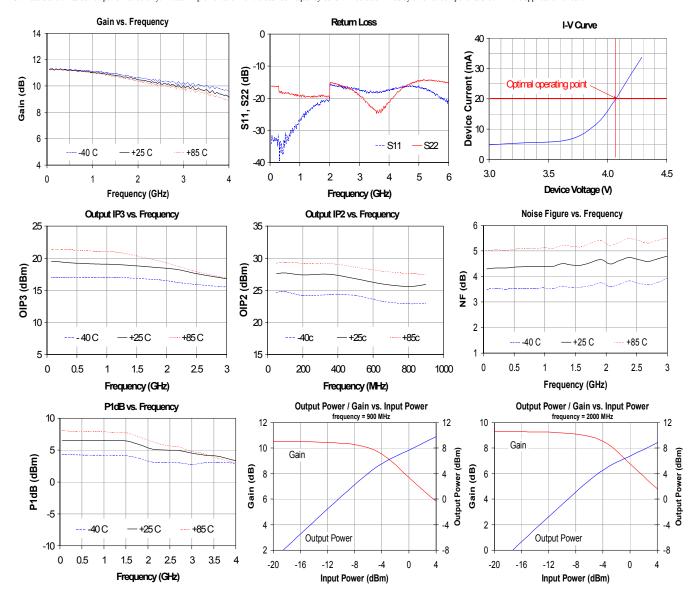


# Typical Device RF Performance Supply Bias = +5 V, $R_{bias}$ = 49.9 $\Omega$ , $I_{cc}$ = 20 mA

Frequency	MHz	100	500	900	1900	2140	2400	3500	5800
S21	dB	11.4	11.4	11.3	11.0	10.9	10.8	10.4	9.2
S11	dB	-30	-30	-25	-20	-15	-16	-18	-20
S22	dB	-16	-16	-16	-16	-16	-16	-20	-14
Output P1dB	dBm	+6.5	+6.5	+6.5	+5.8	+5.1	+5.0	+4.1	
Output IP3	dBm	+19.5	+19.5	+19.1	+18.5	+18.2	+17.7		
Noise Figure	dB	4.3	4.3	4.4	4.6	4.6	4.7		

- Test conditions: T = 25° C, Supply Voltage = +5 V, Device Voltage = 4.0 V, Rbias = 49.9 Ω, Icc = 20 mA typical, 50 Ω System.
- 2. 30IP measured with two tones at an output power of -10 dBm/tone separated by 10 MHz. The suppression on the largest IM3 product is used to calculate the 30IP using a 2:1 rule.

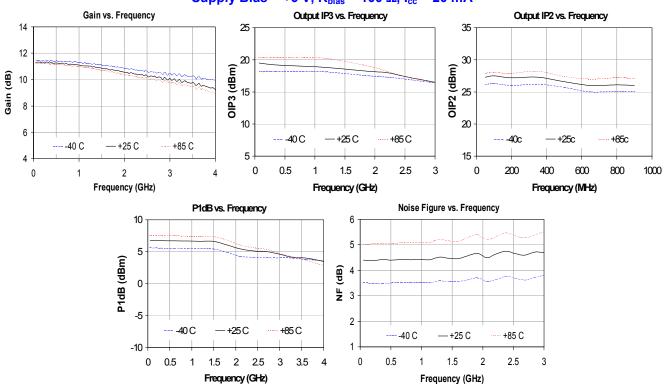
  3. Data is shown as device performance only. Actual implementation for the desired frequency band will be determined by external components shown in the application circuit.





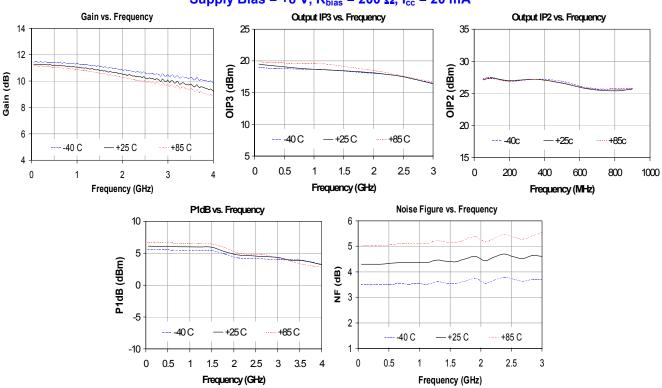
#### **Typical Device RF Performance (cont'd)**

Supply Bias = +6 V,  $R_{bias}$  = 100  $\Omega$ ,  $I_{cc}$  = 20 mA

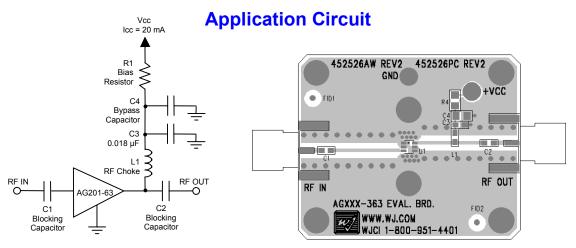


### **Typical Device RF Performance**

Supply Bias = +8 V,  $R_{bias}$  = 200  $\Omega$ ,  $I_{cc}$  = 20 mA







Recommended Component Values

Reference	Frequency (MHz)								
Designator	50	500	900	1900	2200	2500	3500		
L1	820 nH	220 nH	68 nH	27 nH	22 nH	18 nH	15 nH		
C1, C2, C4	.018 μF	1000 pF	100 pF	68 pF	68 pF	56 pF	39 pF		

- 1. The proper values for the components are dependent upon the intended frequency of operation.
- 2. The following values are contained on the evaluation board to achieve optimal broadband performance:

Ref. Desig.	Value / Type	Size
L1	39 nH wirewound inductor	0603
C1, C2	56 pF chip capacitor	0603
C3	0.018 μF chip capacitor	0603
C4	Do Not Place	
R1	49.9 Ω 1% tolerance	0603

#### Recommended Bias Resistor Values

S upply Voltage	R1 value	Size
5 V	50 ohms	0603
6 V	100 ohms	0603
7 V	150 ohms	0805
8 V	200 ohms	0805
9 V	250 ohms	1206
10 V	300 ohms	1210
12 V	400 ohms	1210

The proper value for R1 is dependent upon the supply voltage and allows for bias stability over temperature. WJ recommends a minimum supply bias of +5 V. A 1% tolerance resistor is recommended.

Freq (MHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
50	-33.36	-6.60	11.22	178.53	-16.01	1.78	-16.22	-2.50
250	-34.27	26.40	11.19	172.86	-16.41	0.49	-16.31	-4.04
500	-33.08	106.48	11.19	165.72	-16.39	-3.56	-18.46	-10.33
750	-29.63	86.10	11.15	158.59	-16.32	-5.87	-18.71	-19.75
1000	-26.66	74.33	11.07	151.65	-16.67	-10.07	-19.20	-28.63
1250	-24.09	69.64	11.04	144.43	-16.23	-10.28	-19.49	-42.62
1500	-22.36	64.19	10.96	137.42	-16.24	-11.70	-19.55	-55.66
1750	-20.94	60.32	10.88	130.39	-16.37	-13.92	-19.24	-69.54
2000	-19.57	56.83	10.77	123.52	-16.33	-14.76	-19.04	-82.66
2250	-16.29	43.02	10.61	116.95	-16.37	-17.48	-15.52	-85.89
2500	-16.47	38.44	10.54	112.28	-16.76	-23.47	-16.44	-94.20
2750	-16.81	41.05	10.48	105.22	-16.16	-23.54	-17.38	-103.52
3000	-17.52	42.18	10.38	98.63	-16.10	-23.33	-19.06	-113.34
3250	-18.18	45.78	10.31	92.38	-16.25	-24.50	-21.18	-127.55
3500	-18.21	48.49	10.24	85.82	-16.21	-26.42	-23.63	-155.61
3750	-18.11	50.97	10.08	79.13	-15.99	-29.08	-23.62	163.87
4000	-17.38	54.83	9.98	72.24	-16.06	-32.03	-21.23	140.39
4250	-16.85	56.42	9.83	65.64	-15.97	-34.05	-18.49	125.84
4500	-16.39	56.13	9.67	59.19	-15.80	-36.44	-16.69	120.27
4750	-16.25	53.66	9.51	52.37	-15.80	-38.98	-15.54	116.28
5000	-16.06	51.28	9.39	45.85	-15.85	-42.28	-14.43	116.89
5250	-17.05	44.99	9.23	39.74	-15.85	-44.47	-14.46	117.24
5500	-18.24	33.18	9.07	33.99	-15.76	-45.79	-14.46	117.59
5750	-19.96	22.01	9.03	27.96	-15.43	-49.07	-14.85	122.56
6000	-21.05	8.45	8.95	21.94	-15.61	-50.71	-14.99	122.55

Device S-parameters are available for download on the website at: http://www.wj.com

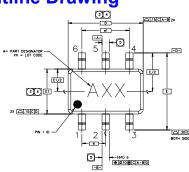


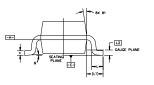
# AG201-63 (SOT-363 Package) Mechanical Information

This package may contain lead-bearing materials. The plating material on the leads is SnI

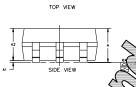
#### **Outline Drawing**







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# D Rating

ion! ESD sensitive device.

Class 0 Passes at 150 V Human Body Model (HBM)

JEDEC Standard JESD22-A114

ESD Rating: Class II Passes at 250 V Value:

Charged Device Model (CDM) Test: JEDEC Standard JESD22-C101 Standard:

MSL Rating: Level 1

JEDEC Standard J-STD-020 Standard:

# **Mounting Config. Notes**

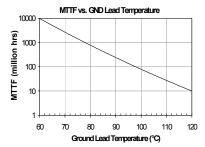
- 1. Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance. Mounting screws can be added near the part to fasten the
- board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink
- 4. Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- 5. RF trace width depends upon the PC board material and
- 6. Use 1 oz. Copper minimum.
- All dimensions are in millimeters (inches). Angles are in

118° C

erenced from the hottest ion to to ground pin (pin 4).

ds typical biasing condition of

85°C case temperature. million hours is achieved for es below 177 °C.



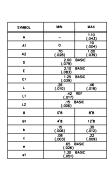
Specifications and information are subject to change without notice

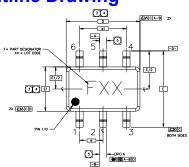


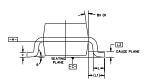
# AG201-63G (Green / Lead-free SOT-363 Package) Mechanical Information

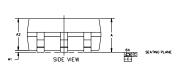
This package is lead-free/Green/RoHS-compliant. It is compatible with both lead-free (maximum 260°C reflow temperature) and leaded (maximum 245°C reflow temperature) soldering processes. The plating material on the leads is annealed matte tin over copper.

#### **Outline Drawing**







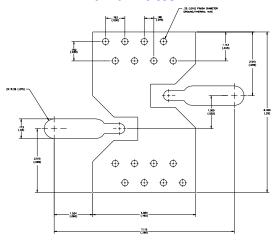


- NOTES:

  1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M-1194, PACKAGE CONFORMS TO JEDEC MO-203, ISSUE B.

  2. DIMENSIONS ARE IN MILLIMETERS (INCHES).
- 3 DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR CATE BURRS, MOLD FLASH, PROTRUSIONS OR CATE BURRS SHALL NOT EXCEED 0.15 mm PER END, DIMENSION ET DOES NOT INCLUDE INTERLEAD FLASH OR PPORTUSION INTERLEAD FLASH OR PPORTUSION SHALL NOT EXCEED 0.15 mm PER SIDE, D AND ET DURSPENSION SERVED TERRANCE A TO A TO A TOTAL ME.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM. DIMENSIONS ON AND ET ARE DETERMED AT THE COTTEMENT CONTINUES. TOTATEMES OF THE PLASTIC BODY EXCULSIVE OF MOLD FLASH. THE BASE BURRS, CAST BURRS AND INTERED AT LASH, BUT INCLUDING MY MISMATCH BETWEEN THE TOP AND THE BOTTOM OF THE PLASTIC BODY, D. AND ET DIMENSIONS ARE DETERMINED.
- 5 DATUM A & B TO BE DETERMINED AT DATUM H
- 6 DIMENSION 'S' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWAGE DAMBAR PROTRUSION. SHALL BE GOOD MIN TOTAL NEXCESS OF THE 'S' DIMENSION AT MANIBUM MATERIAL CONDITION. ARBOIT OF THE FOOT MAINUM MATERIAL CONDITION. RADIUS OF THE FOOT MAINUM SPACE BETWEEN PROTRUSION. AND AN ADJACENT LEAD SHALL NO BE LESS THAN 40.07 mm.

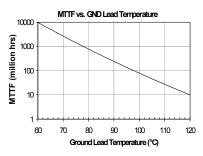
#### **Land Pattern**



# **Thermal Specifications**

Parameter	Rating
Operating Case Temperature	-40 to +85°C
Thermal Resistance, Rth (1)	410° C/W
Junction Temperature, Tjc (2)	118° C

- 1. The thermal resistance is referenced from the part of the junction to the ground pin (pin 4).
- This corresponds to the typical biasing condition of +4.0V, 20 mA at an 85°C case temperature. A minimum MTTF of 1 million hours is achieved for junction temperatures below 177 °C.



### **Product Marking**

The component will be marked with an "F" designator followed by a two-digit numeric lot code on the top surface of the package.

Tape and reel specifications for this part are located on the website in the "Application Notes" section.

### **MSL / ESD Rating**



Caution! ESD sensitive device.

ESD Rating: Class 1C

Value: Passes at 1000 V min.
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

ESD Rating: Class IV

Value: Passes at 1000 V min.

Test: Charged Device Model (CDM) Standard: JEDEC Standard JESD22-C101

MSL Rating: Level 3

Standard: JEDEC Standard J-STD-020

## **Mounting Config. Notes**

- Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25 mm (.010").
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.
- Mounting screws can be added near the part to fasten the board to a heatsink. Ensure that the ground / thermal via region contacts the heatsink.
- Do not put solder mask on the backside of the PC board in the region where the board contacts the heatsink.
- RF trace width depends upon the PC board material and construction.
- Use 1 oz. Copper minimum.
- All dimensions are in millimeters (inches). Angles are in degrees.

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